

Silicon NPN Darlington Power Transistor

GT43

DESCRIPTION

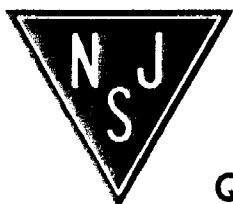
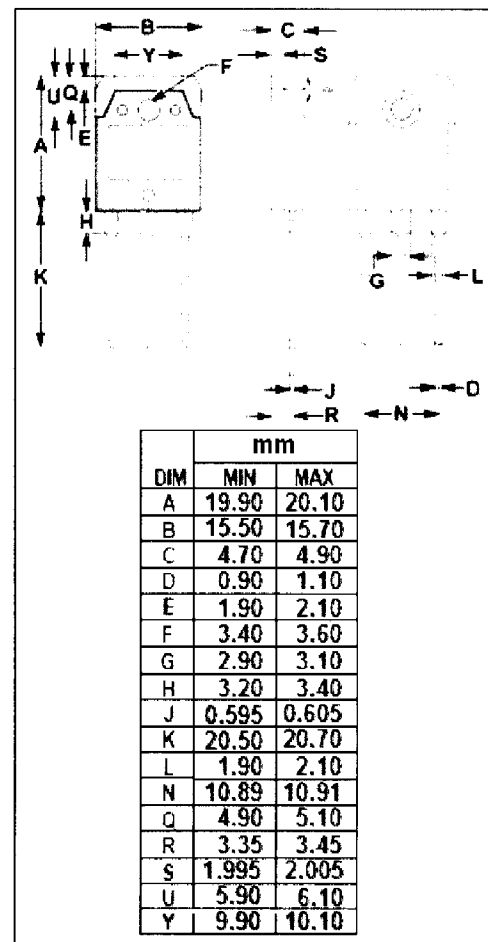
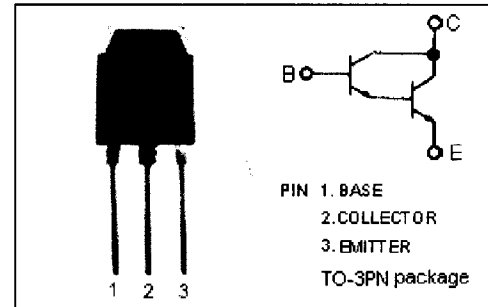
- Collector-Emitter Breakdown Voltage-
: $V_{(BR)CEO} = 300V(\text{Min})$
- High DC Current Gain
: $h_{FE} = 2000(\text{Min.}) @ I_C = 4A$
- Low Collector Saturation Voltage
: $V_{CE(\text{sat})} = 3.0V(\text{Max.}) @ I_C = 6A$

APPLICATIONS

- Switching for dynamotor excitation
- General purpose power amplifier

ABSOLUTE MAXIMUM RATINGS($T_a=25^\circ\text{C}$)

SYMBOL	PARAMETER	VALUE	UNIT
V_{CBO}	Collector-Base Voltage	400	V
V_{CEO}	Collector-Emitter Voltage	300	V
V_{EBO}	Emitter-Base Voltage	7	V
I_C	Collector Current-Continuous	10	A
I_B	Base Current-Continuous	1	A
P_C	Collector Power Dissipation @ $T_C=25^\circ\text{C}$	100	W
T_J	Junction Temperature	150	$^\circ\text{C}$
T_{stg}	Storage Temperature Range	-55~150	$^\circ\text{C}$



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ELECTRICAL CHARACTERISTICS

$T_c=25^\circ\text{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	$I_C=10\text{mA}; I_B=0$	300			V
$V_{(BR)CBO}$	Collector-Base Breakdown Voltage	$I_C=1\text{mA}; I_E=0$	400			V
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage	$I_E=50\text{mA}; I_C=0$	7			V
$V_{CE(sat)-1}$	Collector-Emitter Saturation Voltage	$I_C=1\text{A}; I_B=10\text{mA}$			1.5	V
$V_{CE(sat)-2}$	Collector-Emitter Saturation Voltage	$I_C=6\text{A}; I_B=50\text{mA}$			3.0	V
I_{CBO}	Collector Cutoff Current	$V_{CB}=400\text{V}; I_E=0$			100	μA
I_{EBO}	Emitter Cutoff Current	$V_{EB}=7\text{V}; I_C=0$			100	μA
h_{FE-1}	DC Current Gain	$I_C=4\text{A}; V_{CE}=4\text{V}$	2000			
h_{FE-2}	DC Current Gain	$I_C=5\text{mA}; V_{CE}=4\text{V}$	300			

